

NEW PRODUCT



Infrared Emitting Diode(GaAs) KEL1002A

Description

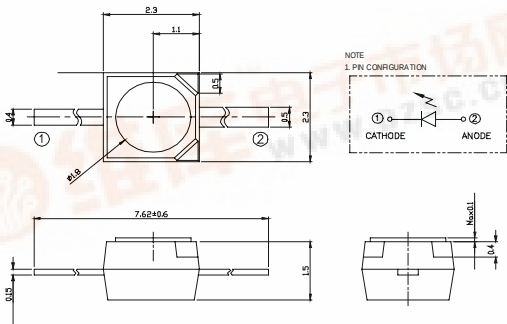
The KEL1002A, high-power GaAs IRED mounted in a clear flat package, is compact, wide radiant angle, and easy to mount.



Features

- High power
- Top view & Small package
- RoHS Compliance
- Wide radiant angle

Outline Dimensions



[Unit : mm]

Application

- Vending machine
- Optical switches
- Optical emitters

Characteristics

[Ta= 25℃]

Description	Symbol	Condition	Min.	Typ.	Max.	Unit
Forward Current	I_F		-	50	-	mA
Reverse Voltage	V_R		-	5	-	V
Power Dissipation	P_D		-	100	-	mW
Radiant intensity	P_O	$I_F=20\text{mA}$	-	0.7	-	mW/sr
Forward Voltage	V_F	$I_F=20\text{mA}$	-	1.2	2.0	V
Peak Wavelength	λ_p	$I_F=20\text{mA}$	-	940	-	nm
Half Angle	$\Delta\theta$		-	± 55	-	deg.

